NSN 5961-01-447-6615

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-447-6615 **Inclosure Material:** Plastic **Overall Length:** 0.190 inches **Overall Height:** 0.140 inches **Overall Width:** 0.190 inches **Function For Which Designed:** Amplifier and switching **End Application:** 6625-01-377-6166 ohmmeter **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 20.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No